are ideal detectors for working with very small, weakly diffracting samples. However, to date these detectors have employed delay-line-based readout electronics which have limited their global counting rate to less than 2 million X-rays/sec. While this is acceptable for most laboratory experiments it is clearly too slow for many beamline experiments. We have therefore undertaken a collaboration to develop a much faster readout based on the BLADE3 readout system developed at the ESRF. We report on the operating characteristics of the microgap detector and the design and characterization of the fast readout system.

Keywords: X-ray detector technology, area detectors, photon-counting detectors

MS.97.3

The PILATUS detectors: Hybrid pixel detectors for synchrotron and industrial applications
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The PILATUS detectors are large area, single photon counting hybrid pixel detectors. PILATUS detectors were developed at the Paul Scherrer Institut (PSI) in Switzerland for the Swiss Light Source. The PILATUS modules are assemblies of 16 CMOS chips bump-bonded to one silicon sensor, with 487 x 195 pixels of 0.172 x 0.172 mm² leading to an area of 8.4 x 3.4 cm². With more than 6 million pixels covering an area of 43.1 x 44.8 cm² the Pilatus 6M detector is the largest such device constructed to date. The detector is comprised of 60 modules, which are mounted on a precision frame. The main feature of the detector is its dynamic range of 20 bits, i.e. more than 1 million X-rays can be stored in each pixel. A massive parallel readout of the detector results in a readout time of 3.6 ms and a frame rate of 12 Hz is achieved. Other important features are the narrow point spread function, the absence of electronic noise, an electronic shutter and the possibility to suppress fluorescent background from the sample. The Pilatus 6M is in operation since spring 2007 at the protein crystallography beamline X06SA of the SLS. The detector is an order of magnitude faster than comparable CCDs and produces data of unprecedented quality.

Keywords: active pixel detectors, protein crystallography, single photon counting

MS.97.5

The 2D X-ray detector development program for the European XFEL
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The European X-Ray Free Laser Facility (XFEL) poses extreme challenges to the design of the 2D imaging detectors, their readout electronics and the data acquisition architecture. Up to 30,000 photon pulses per second, each offering unprecedented intensities in the order of 10^12 photons per pulse with quasi instantaneous energy deposition require the adoption of novel detector and readout schemes. The large variability in the pulse patterns and the relatively large pulse to pulse variations inherent in the XFEL pulse generation process need to be coped with. The requirements from the scientific instruments for the detectors focus on size, granularity, signal to noise and dynamic range. The high intensity environment poses new challenges with respect to radiation hardness, detection speed and frame rate capabilities. One 2D X-Ray detector with 1k by 1k pixels and a readout frame rate of 5000 per second will generate approximately 10Gbyte of data per second, requiring complex architectures to direct the data flow to storage. In this contribution, the development program for the different 2D X-Ray imaging detectors for the European XFEL and the related data acquisition and control architecture will be described.

Keywords: detector development, imaging, flat panel

MS.97.4

Monolithic active-matrix silicon X-ray detectors
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Two types of X-ray Active Matrix Pixel Sensor (XAMPS) were designed and fabricated: one, based on J-FET technology, has a pixel size of 90um, is 400um-thick and was fabricated at Brookhaven National Laboratory (BNL); the other, based on PMOS technology, has a pixel size of 60um, is 725-um thick and was fabricated at IBM’s T. J. Watson Research Center. The prototypes are square matrices with n rows and n columns with n = 16, 32, 64, 128, 256, 512 for the BNL production and n = 32, 64, 128, 256, 512, 1024 for the IBM one. The XAMPS is a position sensitive ionization detector made on high resistivity silicon. It consists of a pixel array detector with integrated switches. Pixels are isolated from each other by a potential barrier and the device is fully depleted by applying a high voltage bias to the junction on the entrance window of the sensor. When the photon is absorbed, the generated electron charge drifts to the exit side of the device and is stored on a capacitor which occupies most of the pixel area. The switches are opened during this phase (data accumulation) and then closed (data readout) to allow the charge to flow to the drain, connected to readout lines. This sensor is highly efficient at the typical range of energy of interest for protein crystallography. It has ~100% fill factor, low noise, millisecond readout, single photon sensitivity and a dynamic range of more than 104 photons per frame. It can be tiled to form bigger area detectors. Future developments could include on-pixel amplifier or small 3T (three-transistors) design.

Keywords: detector development, imaging, flat panel